## DATA SHEET

# SILICON POWER TRANSISTOR **2SA1649,1649-Z**

### PNP SILICON EPITAXIAL TRANSISTOR FOR HIGH-SPEED SWITCHING

#### DESCRIPTION

NEC

The 2SA1649 is a mold power transistor developed for high-speed switching and features a very low collector-to-emitter saturation voltage.

This transistor is ideal for use in switching regulators, DC/DC converters, motor drivers, solenoid drivers, and other low-voltage power supply devices, as well as for high-current switching.

#### **FEATURES**

- · Available for high-current control in small dimension
- Z type is a lead processed product and is deal for mounting a hybrid IC.
- Mold package that does not require an insulating board or insulation bushing
- Low collector saturation voltage:
   V<sub>CE(sat)</sub> = -0.3 V MAX. (Ic = -3 A)
- Fast switching speed:
- $t_f = 0.3 \ \mu s MAX. (Ic = -3 A)$
- · High DC current amplifiers and excellent linearity

#### ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	Vсво	-40	V
Collector to emitter voltage	VCEO	-30	V
Emitter to base voltage	VEBO	-7.0	V
Collector current (DC)	IC(DC)	-10	А
Collector current (pulse)	Note 1	-20	А
Base current (DC)	B(DC)	-3.5	А
Total power dissipation	P⊤ (Tc = 25 °C)	15	W
Total power dissipation	P⊤ (Ta = 25 °C)	1.0 <sup>Note 2</sup> , 2.0 <sup>Note 3</sup>	W
Junction temperature	Tj	150	°C
Storage temperature	Tstg	–55 to +150	°C

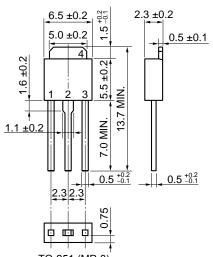
Notes 1.  $PW \le 300 \text{ ms}$ , Duty Cycle  $\le 10\%$ 

2. Printing board mounted

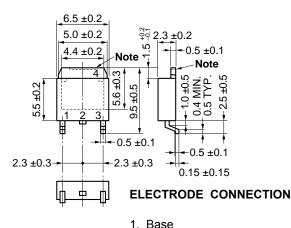


**3.** 7.5 cm<sup>2</sup>  $\times$  0.7 mm ceramic board mounted

<R> PACKAGE DRAWINGS (Unit: mm)







- TO-252 (MP-3Z) 2 Coll
  - ) 2. Collector
    - 3. Emitter
    - 4. Collector Fin

**Note** The depth of notch at the top of the fin is from 0 to 0.2 mm.

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The mark <R> shows major revised points.

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The revised points can be easily searched by copying an "<R>" in the PDF file and specifying it in the "Find what:" field.

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

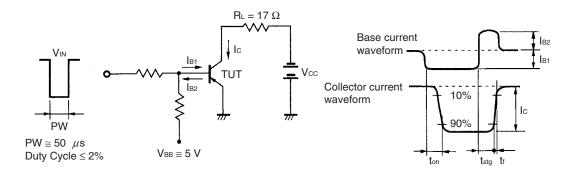
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector to emitter voltage	VCEO(SUS)	$I_{C} = -4.0 \text{ A}, I_{B} = -0.4 \text{ A}, L = 1 \text{ mH}$	-30			V
Collector to emitter voltage	VCEX(SUS)	Ic = -4.0 A, I <sub>B2</sub> = -I <sub>B1</sub> = -0.4 A, V <sub>BE(OFF)</sub> = 1.5 V, L = 180 $\mu$ H, clamped	-40			V
Collector cutoff current	Ісво	Vce = -30 V, Ie = 0			-10	μA
Collector cutoff current	ICER	Vce = $-30$ V, Rbe = $50 \Omega$ , Ta = $125^{\circ}$ C			-1.0	mA
Collector cutoff current	ICEX1	$V_{CE} = -30 \text{ V}, \text{ V}_{BE(OFF)} = 1.5 \text{ V}$			-10	μA
Collector cutoff current	ICEX2	$V_{CE} = -30 \text{ V}, \text{ V}_{BE(OFF)} = 1.5 \text{ V},$ Ta = 125°C			-1.0	mA
Emitter cutoff current	Іево	$V_{EB} = -5.0 \text{ V}, \text{ Ic} = 0$			-10	μA
DC current gain	hfe1 Note	Vce = -2.0 V, Ic = -0.5 A	100			_
DC current gain	hfe2 Note	Vce = -2.0 V, Ic = -2.0 A	100	200	400	_
DC current gain	hfe3 Note	$V_{CE} = -2.0 \text{ V}, \text{ Ic} = -4.0 \text{ A}$	60			-
Collector saturation voltage	VCE(sat)1 Note	Ic = −3.0 A, I <sub>B</sub> = −0.2 A			-0.3	V
Collector saturation voltage	VCE(sat)2 Note	$I_{\rm C} = -4.0$ A, $I_{\rm B} = -0.3$ A			-0.5	V
Base saturation voltage	VBE(sat)1 Note	Ic = −3.0 A, I <sub>B</sub> = −0.2 A			-1.2	V
Base saturation voltage	VBE(sat)2 Note	$I_{C} = -4.0 \text{ A}, I_{B} = -0.3 \text{ A}$			-1.5	V
Collector capacitance	Cob	Vсв = -10 V, IE = 0, f = 1.0 MHz		250		pF
Gain bandwidth product fr		Vce = -10 V, Ic = -0.5 A		120		MHz
Turn-on time	ton	$I_{C} = -4.0 \text{ A}, \text{ R}_{L} = 5 \Omega,$			0.3	μS
Storage time	tstg	$I_{B1} = -I_{B2} = -0.15 \text{ A}, \text{ Vcc} \cong -20 \text{ V}$ Refer to the test circuit.			1.5	μS
Fall time	tr				0.3	μs

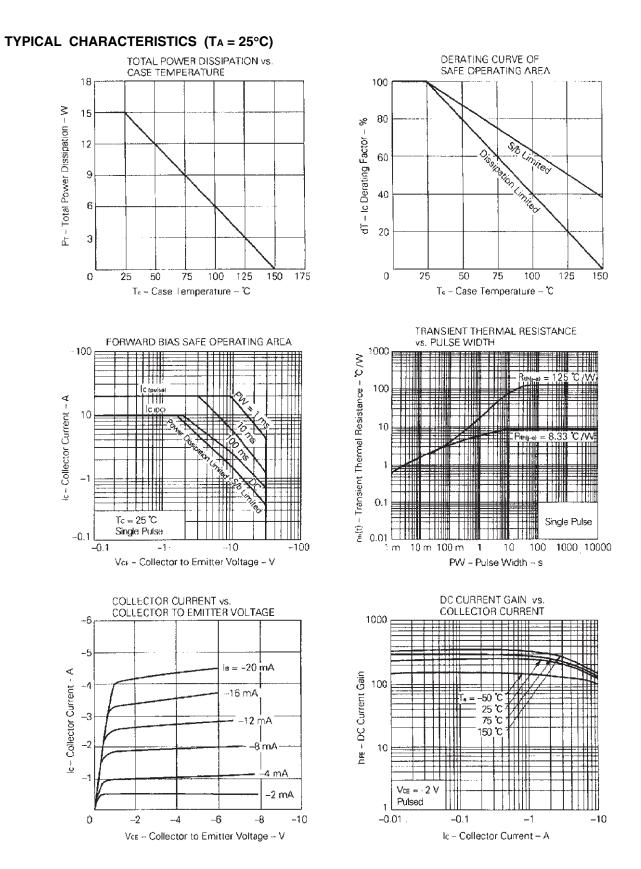
**Note** Pulse test PW  $\leq$  350  $\mu$ s, duty cycle  $\leq$  2%/pulsed

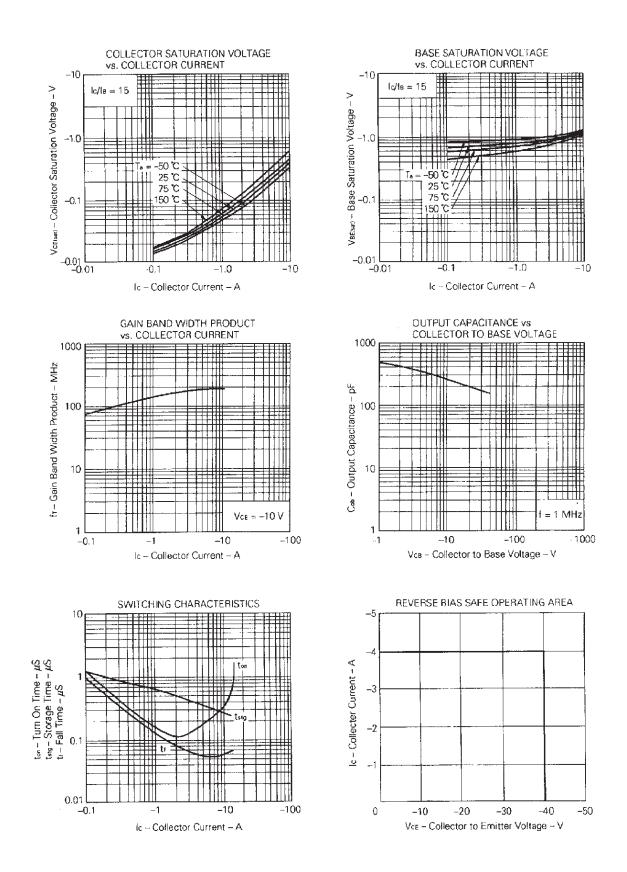
#### **hfe CLASSIFICATION**

Marking	М	L	к
hFE2	100 to 200	150 to 300	200 to 400

SWITCHING TIME (ton, tstg, tf) TEST CIRCUIT







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